

DIGITAL IC DESIGN ELECTIVE-III

OBJECTIVES

- The student will be able to understand the MOS Design.
- In this course, students can study Combinational MOS Logic Circuits and Sequential MOS Logic Circuits.
- Another main object of this course is to motivate the graduate students to design and to develop the Digital Integrated Circuits for different Applications.
- The concepts of Semiconductor Memories, Flash Memory, RAM array organization.

UNIT-I:

MOS Design: Pseudo NMOS Logic – Inverter, Inverter threshold voltage, Output high voltage, Output Low voltage, Gain at gate threshold voltage, Transient response, Rise time, Fall time, Pseudo NMOS logic gates, Transistor equivalency, CMOS Inverter logic.

UNIT-II:

Combinational MOS Logic Circuits: MOS logic circuits with NMOS loads, Primitive CMOS logic gates – NOR & NAND gate, Complex Logic circuits design – Realizing Boolean expressions using NMOS gates and CMOS gates, AOI and OIA gates, CMOS full adder, CMOS transmission gates, Designing with Transmission gates.

UNIT-III:

Sequential MOS Logic Circuits: Behaviour of bistable elements, SR Latch, Clocked latch and flip flop circuits, CMOS D latch and edge triggered flip-flop.

UNIT-IV:

Dynamic Logic Circuits: Basic principle, Voltage Bootstrapping, Synchronous dynamic pass transistor circuits, Dynamic CMOS transmission gate logic, High performance Dynamic CMOS circuits.

UNIT-V:

Interconnect: Capacitive Parasitics, Resistive Parasitics, Inductive Parasitics, Advanced Interconnect Techniques.

UNIT-VI:

Semiconductor Memories: Memory Types, RAM array organization, DRAM – Types, Operation, Leakage currents in DRAM cell and refresh operation, SRAM operation Leakage currents in SRAM cells, Flash Memory- NOR flash and NAND flash.

Text Books:

1. Digital Integrated Circuits – A Design Perspective, Jan M. Rabaey, Anantha Chandrakasan, Borivoje Nikolic, 2nd Ed., PHI.
2. Digital Integrated Circuit Design – Ken Martin, Oxford University Press, 2011.

References:

1. CMOS Digital Integrated Circuits Analysis and Design – Sung-Mo Kang, Yusuf Leblebici, TMH, 3rd Ed., 2011.
2. CMOS VLSI Design – Neil H.E Weste, David harris, Ayan Banerjee 3rd Edition, Pearson

OUTCOMES

After going through this course the student will be able to

- Understand the concepts of MOS Design.
- Design and analysis of Combinational and Sequential MOS Circuits.
- Extend the Digital IC Design to Different Applications.
- Understand the Concepts of Semiconductor Memories, Flash Memory, RAM array organization.